Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

Between 0.140 inches and 0.160 inches

Terminal Length:

1.125 inches

Overall Diameter:

Between 0.130 inches and 0.150 inches

End Application:

P/n3046b; strategic weapon system (poseidon & trident), general purpose electronic test equipment gpete, ticonderoga class cg (47), spruance class dd (963), los angeles class ssn (688), forrestal class cv, nimitz class cvn; support equipment, f-111 aircraft

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do-35

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Criticality Code Justification:

Feat

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

9.3 regulator voltage

Current Rating Per Characteristic:

11.00 milliamperes source cutoff current horsepower metric

Power Rating Per Characteristic:

0.4 watts small-signal input power, common-collector absolute

Special Features:

Weapon system essential; junction pattern arrangement: pn

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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